

Features

- Ultra low capacitance: 25 pF Max
- Ultra low leakage: nA level
- Low operating voltage: $\pm 5V$
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - – IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30kV$
 - Contact discharge: $\pm 30kV$
 - – IEC61000-4-5 (Lightning)8A (8/20 μs)
- RoHS Compliant
- Lead Finish: NiPdAu

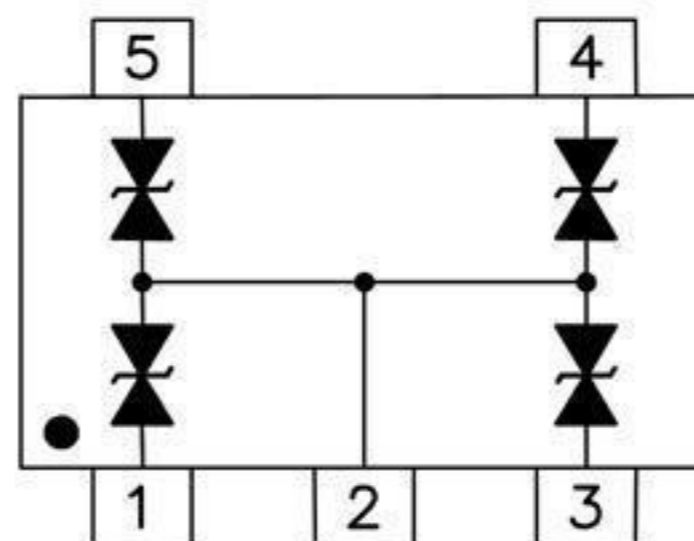
Mechanical Characteristics

- ◆ Package: SOT23-5
- ◆ Lead Finish: Matte Tin
- ◆ Case Material: "Green" Molding Compound.
- ◆ UL Flammability Classification Rating 94V-0
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Shipping Qty :3000/7Inch Tape & Reel

Applications

- ◆ Cell phone Handsets and Accessories
- ◆ Microprocessor Based Equipment
- ◆ Personal Digital Assistants (PDA's)
- ◆ Notebooks, Desktops, and Servers
- ◆ Portable Instrumentation
- ◆ Set Top Box

Dimensions and Pin Configuration



Absolute Maximum Ratings (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	80	W
Peak Pulse Current (8/20μs)	Ipp	8	A
ESD per IEC 61000-4-2 (Air)	VESD	±25	kV
ESD per IEC 61000-4-2 (Contact)		±25	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	5.6		8.4	V	IT = 1mA
Reverse Leakage Current	IR			0.08	uA	VRWM = 5V
Clamping Voltage	VC			6	V	Ipp=1A(8x 20us pulse)
Clamping Voltage	VC			10	V	Ipp=8A(8x 20us pulse)
Junction Capacitance	CJ			25	pF	VR = 0V, f = 1MHz IO to IO

Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)

Fig1. 8/20 μs Pulse Waveform

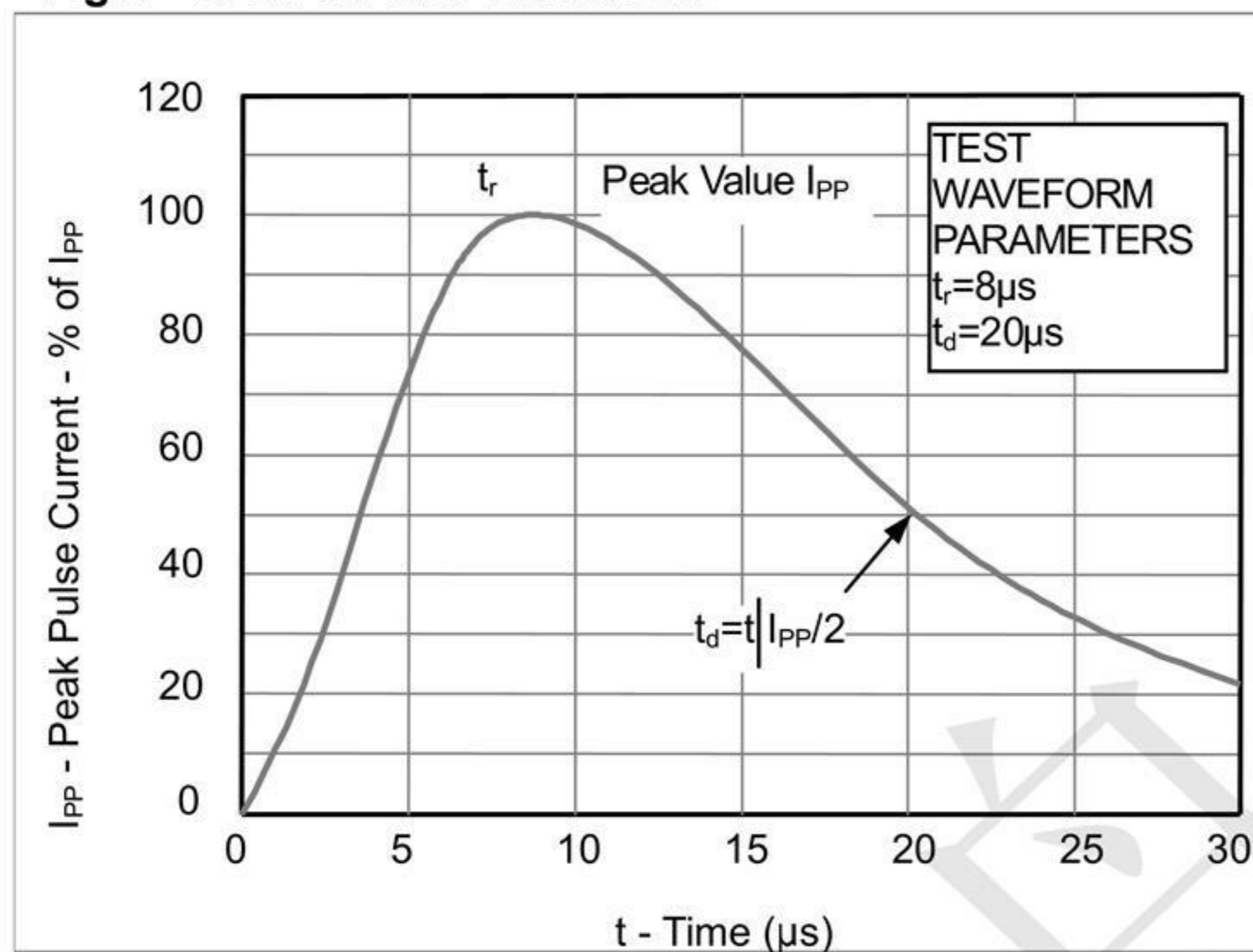


Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)

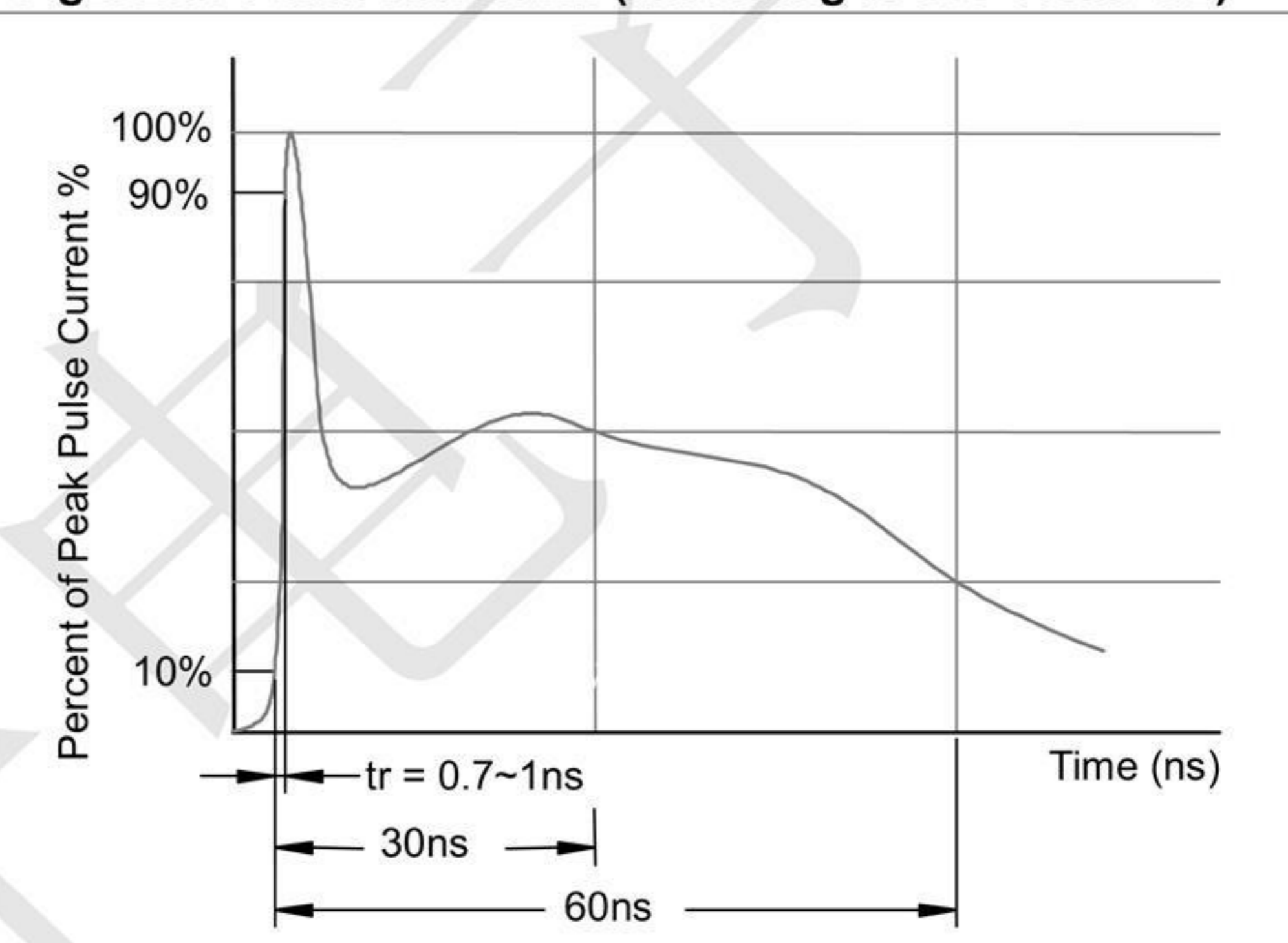
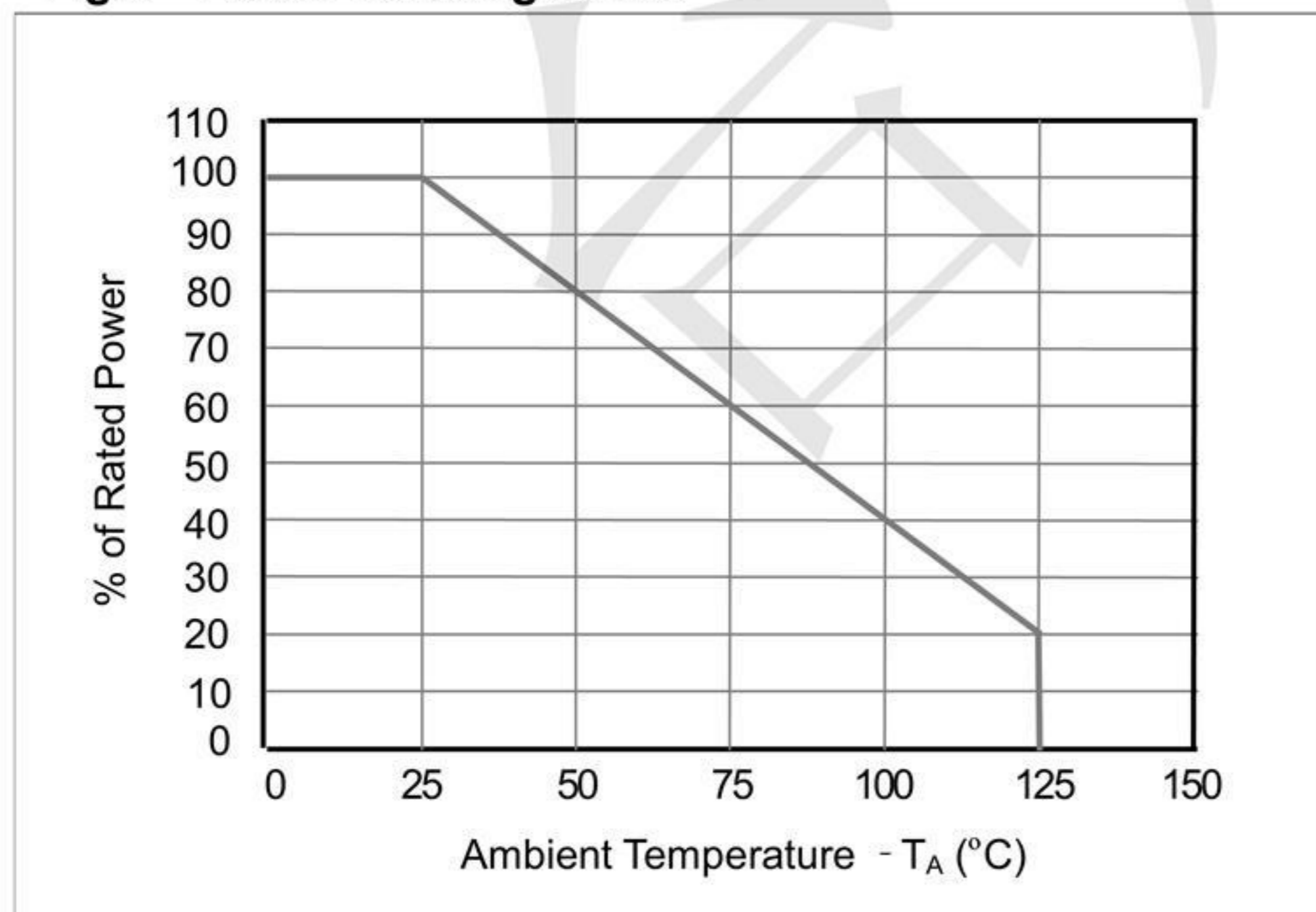
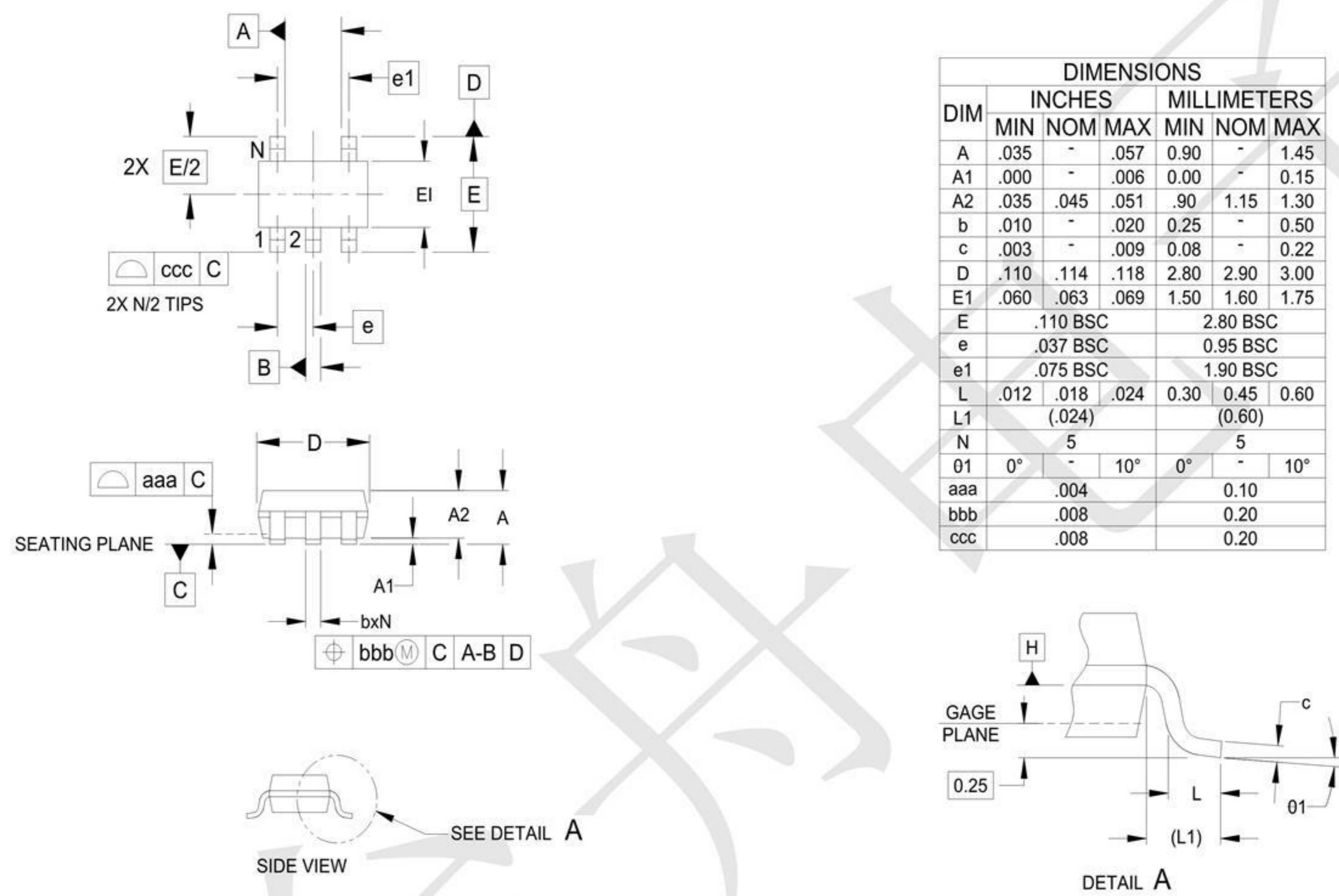


Fig3. Power Derating Curve



SOT23-5 Package Outline Drawing



Suggested Land Pattern

